1. General description

The 74HC112-Q100; 74HCT112-Q100 is a dual negative-edge triggered JK flip-flop. It features individual J and K inputs, clock ($n\overline{CP}$) set ($n\overline{SD}$) and reset ($n\overline{RD}$) inputs. It also has complementary nQ and nQ outputs. The set and reset are asynchronous active LOW inputs and operate independently of the clock input. The J and K inputs control the state changes of the flip-flops as described in the mode select function table. The J and K inputs must be stable one set-up time prior to the HIGH-to-LOW clock transition for predictable operation. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

2. Features and benefits

- Input levels:
 - For 74HC112-Q100: CMOS level
 - For 74HCT112-Q100: TTL level
- Asynchronous set and reset
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

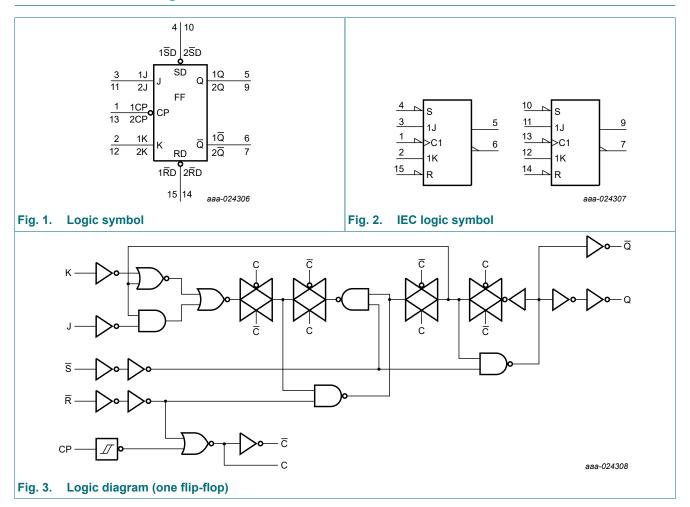
3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74HCT112D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				
74HC112PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

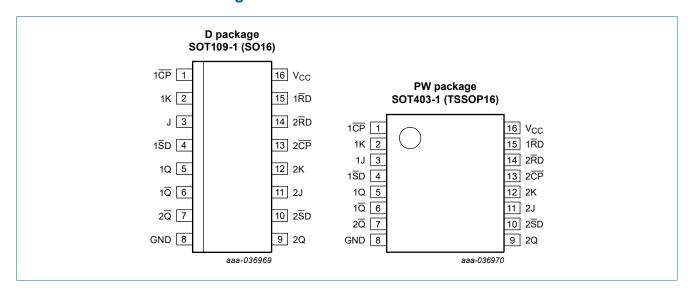


4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP, 2CP	1, 13	clock input (HIGH-to-LOW; edge-triggered)
1K, 2K	2, 12	data input
1J, 2J	3, 11	data input
1SD, 2SD	4, 10	set input (active LOW)
1Q, 2Q	5, 9	true flip-flop output
1Q, 2Q	6, 7	complement flip-flop output
GND	8	ground (0 V)
1RD, 2RD	15, 14	reset input (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function selection

If $n\overline{S}D$ and $n\overline{R}D$ simultaneously go from LOW-to-HIGH, the output states are unpredictable.

H = HIGH voltage level; h = HIGH voltage level one set-up time before the HIGH-to-LOW clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time before the HIGH-to-LOW clock transition;

q = lowercase letters indicate the state of the referenced output one set-up time before the HIGH-to-LOW clock transition;

 $X = don't care; \downarrow = HIGH-to-LOW clock transition.$

Operating modes	Input			Output			
	n <mark>S</mark> D	nRD	nCP	nJ	nK	nQ	nQ
Asynchronous set	L	Н	Х	Х	X	Н	L
Asynchronous reset	Н	L	Х	Х	Х	L	Н
Undetermined	L	L	Х	Х	X	Н	L
Toggle	Н	Н	\	h	h	q	q
Load 0 (reset)	Н	Н	\	I	h	L	Н
Load 1 (set)	Н	Н	\downarrow	h	I	Н	L
Hold no change	Н	Н	\	Į	I	q	q

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	-0.5 V < V _O < V _{CC} + 0.5 V		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation		[1]	-	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	741	74HC112-Q100		74HCT112-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	;	-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC112	2-Q100									
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

Symbol	Parameter	Conditions		25 °C	;	-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	٧
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	٧
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	٧
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	4.0	-	40	-	80	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	12-Q100	1								
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	8.0	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	Ι _Ο = -20 μΑ	4.4	4.5	-	4.4	-	4.4	-	٧
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 5.5 V	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V								
		nSD inputs	-	50	180	-	225	-	245	μΑ
		nK inputs	-	60	216	-	270	-	294	μA
		nRD inputs	-	65	236	-	293	-	319	μΑ
		nJ, and nCP inputs	-	100	360	-	450	-	490	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Fig. 6.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
74HC112	2-Q100							1		
t _{pd}	propagation	nCP to nQ; see Fig. 4 [2]								
	delay	V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nCP to nQ; see Fig. 4								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nRD to nQ, nQ; see Fig. 5								
		V _{CC} = 2.0 V	-	58	180	-	225	-	270	ns
		V _{CC} = 4.5 V	-	21	36	-	45	-	54	ns
		V _{CC} = 5 V; C _L = 15 pF	-	18	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	17	31	-	38	-	46	ns
		nSD to nQ, nQ; see Fig. 5								
		V _{CC} = 2.0 V	-	50	155	-	295	-	235	ns
		V _{CC} = 4.5 V	-	18	31	-	39	-	47	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	40	ns
t _t	transition	$nQ, n\overline{Q}; see Fig. 4$ [3]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	nCP HIGH or LOW; see Fig. 4								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		nSD, nRD LOW; see Fig. 5								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t _{rec}	recovery time	nRD to nCP; see Fig. 5								
		V _{CC} = 2.0 V	80	22	-	125	-	150	-	ns
		V _{CC} = 4.5 V	16	8	-	25	-	30	-	ns
		V _{CC} = 6.0 V	14	6	-	21	-	26	-	ns
		nSD to nCP; see Fig. 5								
		V _{CC} = 2.0 V	80	-19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	-7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	-6	-	17	-	20	-	ns
t _{su}	set-up time	nJ and nK to nCP; see Fig. 4								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _h	hold time	nJ and nK to nCP; see Fig. 4								
		V _{CC} = 2.0 V	0	-11	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-4	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-3	-	0	-	0	-	ns
f _{max}	maximum	nCP; see Fig. 4								
	frequency	V _{CC} = 2.0 V	6	20	-	4.8	-	4.0	-	MHz
		V _{CC} = 4.5 V	30	60	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	66	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	71	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f = 1 \text{ MHz}; $ [4] $V_I = \text{GND to } V_{CC}$	-	27	-			-	-	pF
74HCT1	12-Q100				l					
t _{pd}	propagation	nCP to nQ; see Fig. 4 [2]								
	delay	V _{CC} = 4.5 V	-	21	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nCP to nQ; see Fig. 4								
		V _{CC} = 4.5 V	-	23	40	-	50	-	60	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nRD to nQ, nQ; see Fig. 5								
		V _{CC} = 4.5 V	-	22	37	-	46	-	56	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nSD to nQ, nQ; see Fig. 5								
		V _{CC} = 4.5 V	-	18	32	-	40	-	48	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
t _t	transition	nQ, nQ; see Fig. 4 [3]								
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	nCP HIGH or LOW; see Fig. 4								
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		nSD, nRD LOW; see Fig. 5								
		V _{CC} = 4.5 V	18	10	-	23	-	27	-	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t _{rec}	recovery time	nRD to nCP; see Fig. 5								
		V _{CC} = 4.5 V	20	11	-	25	-	30	-	ns
		nSD to nCP; see Fig. 5								
		V _{CC} = 4.5 V	20	-8	-	25	-	30	-	ns
t _{su}	set-up time	nJ and nK to n CP ; see <u>Fig. 4</u>								
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
t _h	hold time	nJ and nK to nCP; see Fig. 4								
		V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
f _{max}	maximum	nCP; see Fig. 4								
	frequency	V _{CC} = 4.5 V	30	64	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	70	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; [4] V_I = GND to V_{CC}	-	30	-	-	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.

- [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] t_t is the same as t_{THL} and t_{TLH}.
 [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit

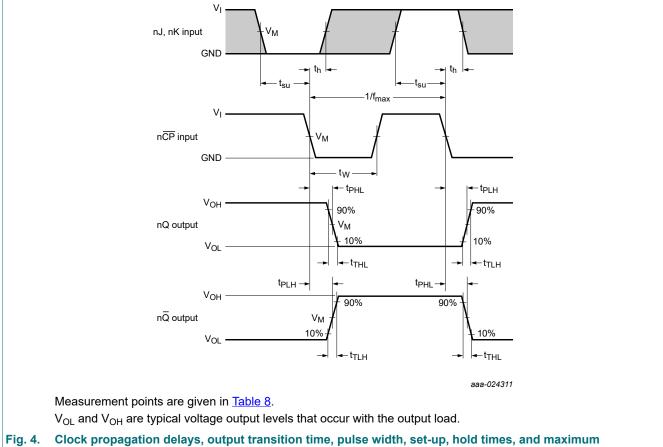


Fig. 4. Clock propagation delays, output transition time, pulse width, set-up, hold times, and maximur frequency

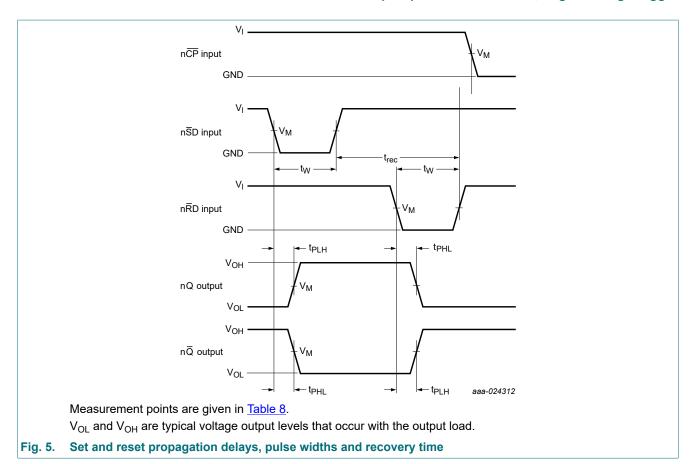
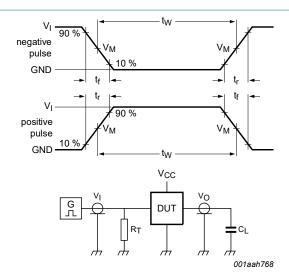


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC112-Q100	0.5 × V _{CC}	0.5 × V _{CC}
74HCT112-Q100	1.3 V	1.3 V

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Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator;

 C_L = Load capacitance including jig and probe capacitance.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Туре	Input		Load	Test
	V _I	t _r , t _f	CL	
74HC112-Q100	V _{CC}	6 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT112-Q100	3 V	6 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

11. Package outline

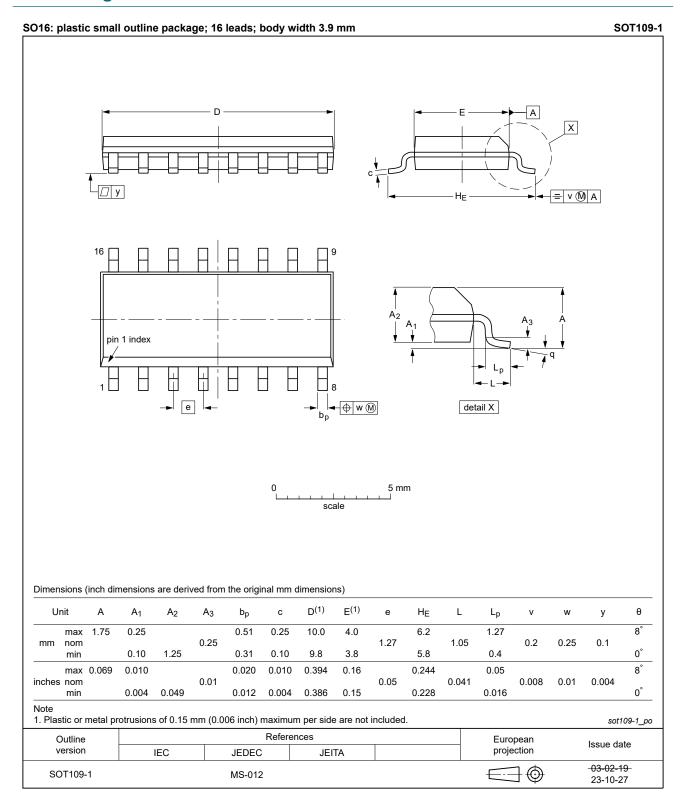


Fig. 7. Package outline SOT109-1 (SO16)

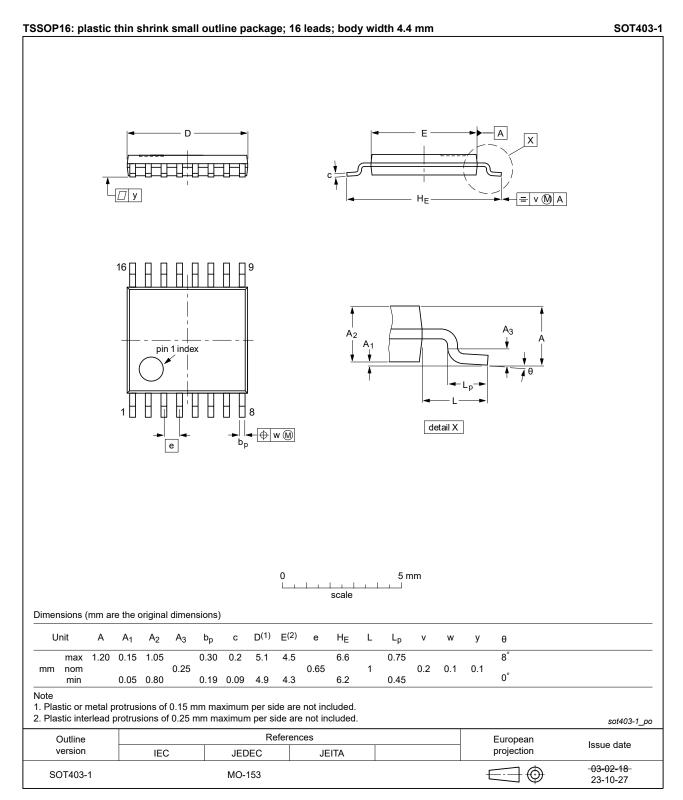


Fig. 8. Package outline SOT403-1 (TSSOP16)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT112_Q100 v.1	20240115	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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